



GaN FET Technology

200 Watt Series

Small Size Desktop Type

ATS200TS - ☐ X X X

P : C6 / C14 ← O / P Voltage
A : C8



Features :

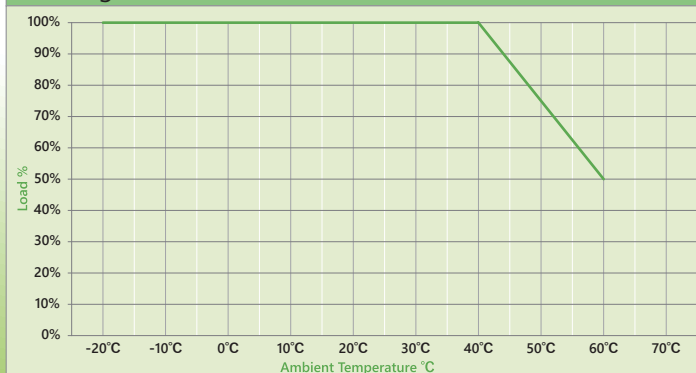
- IEC/EN/UL 62368-1
- 100-240 VAC Universal Input
- Gallium Nitride Based Design
- High Power Density : 12.5W / in³
- With 250kHz Switching Frequency
- Efficiency up to 95%
- Regulated Output with Low Ripple Noise
- Modified and Custom Design Available
- 1 Year Warranty

Model	O/P Voltage	O/P Current	Watt
ATS200TS- ☐ 120	12.0V	16.0A	192W
ATS200TS- ☐ 180	18.0V	11.1A	200W
ATS200TS- ☐ 190	19.0V	10.5A	200W
ATS200TS- ☐ 191	19.5V	10.2A	200W
ATS200TS- ☐ 200	20.0V	10.0A	200W
ATS200TS- ☐ 240	24.0V	8.3A	200W
ATS200TS- ☐ 480	48.0V	4.2A	200W
ATS200TS- ☐ 560	56.0V	3.6A	200W

Input

Voltage	100-240VAC
Line Frequency	50-60Hz
Current	2.4A Max.
Protection	Internal Primary Current Fuse
Configuration	IEC60320/C6, C8, C14

Derating Curve



Output

Load Regulation	± 5% (Typical)
Ripple & Noise	≤ 1% Vp-p @ Full Load
Transient (Dynamic) Response	0.5mS with 50% Load Change
Start-up Time	< 3,000mS
Hold-up Time	≥ 10mS @ Full Load
Rise Time	< 50mS
Protection	Short Circuit Protection / Over Voltage Protection / Over Current Protection / Over Temperature Protection

Electrical

Topology	LLC
Dielectric Withstand	3,000VAC Primary - Secondary
Leakage Current	< 0.5mA @ 2Pin / < 5mA @ 3Pin
Efficiency	DoE Level VI, ErP Stage 2, CoC Tier 2
EMC Standards	EN55032 EN61000-3-2,3 EN55035
MTBF	300,000 Calculated Hours at 25°C, by Telcordia SR-332

Environmental

Operating Temperature	-20 to + 40°C
Storage Temperature	-20 to + 80°C
Operating Altitude	5,000M
Relative Humidity	Operating : 20 to 80% RH Storage : 10 to 90% RH
Cooling	Natural Convection Cooling

Mechanical

Case Dimension	C6 & C14 - L 161 × W 54.2 × H 33.2 (mm) C8 - L 150 × W 54 × H 33 (mm)
Weight	560g (Ref.)